

## N-CHANNEL MOS FIELD EFFECT TRANSISTOR FOR SWITCHING

### DESCRIPTION

The  $\mu$ PA1872 is a switching device which can be driven directly by a 2.5 V power source.

This device features a low on-state resistance and excellent switching characteristics, and is suitable for applications such as power switch of portable machine and so on.

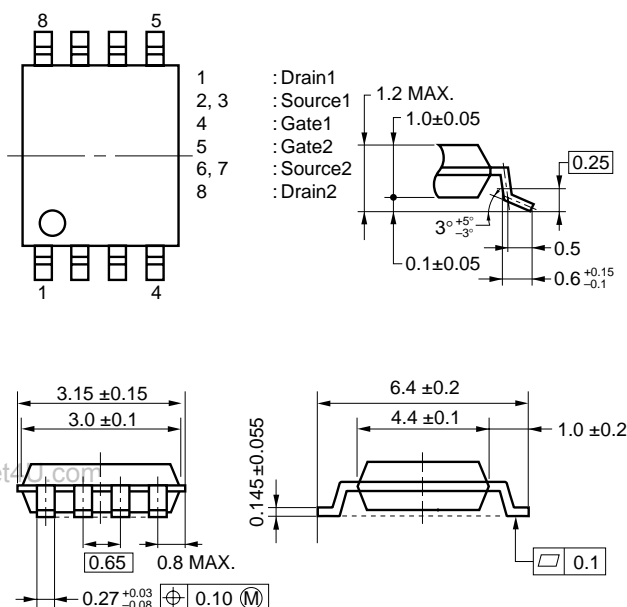
### FEATURES

- 2.5 V drive available
- Low on-state resistance
  - $R_{DS(on)1} = 13.0 \text{ m}\Omega \text{ MAX. (} V_{GS} = 4.5 \text{ V, } I_D = 5.0 \text{ A)}$
  - $R_{DS(on)2} = 13.5 \text{ m}\Omega \text{ MAX. (} V_{GS} = 4.0 \text{ V, } I_D = 5.0 \text{ A)}$
  - $R_{DS(on)3} = 15.5 \text{ m}\Omega \text{ MAX. (} V_{GS} = 3.1 \text{ V, } I_D = 5.0 \text{ A)}$
  - $R_{DS(on)4} = 18.0 \text{ m}\Omega \text{ MAX. (} V_{GS} = 2.5 \text{ V, } I_D = 5.0 \text{ A)}$
- Built-in G-S protection diode against ESD

### ORDERING INFORMATION

PART NUMBER	PACKAGE
$\mu$ PA1872GR-9JG	Power TSSOP8

### PACKAGE DRAWING (Unit : mm)



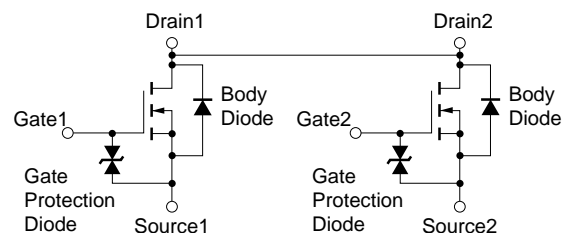
### ABSOLUTE MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ )

Drain to Source Voltage ( $V_{GS} = 0 \text{ V}$ )	$V_{DSS}$	20	V
Gate to Source Voltage ( $V_{DS} = 0 \text{ V}$ )	$V_{GSS}$	$\pm 12$	V
Drain Current (DC) ( $T_A = 25^\circ\text{C}$ )	$I_{D(DC)}$	$\pm 10$	A
Drain Current (pulse) <sup>Note1</sup>	$I_{D(pulse)}$	$\pm 80$	A
Total Power Dissipation (2 unit) <sup>Note2</sup>	$P_T$	2.0	W
Channel Temperature	$T_{ch}$	150	$^\circ\text{C}$
Storage Temperature	$T_{stg}$	-55 to +150	$^\circ\text{C}$

- Notes**
1.  $PW \leq 10 \mu\text{s}$ , Duty Cycle  $\leq 1\%$
  2. Mounted on ceramic substrate of  $5000 \text{ mm}^2 \times 1.1 \text{ mm}$

**Remark** The diode connected between the gate and source of the transistor serves as a protector against ESD. When this device actually used, an additional protection circuit is externally required if a voltage exceeding the rated voltage may be applied to this device.

### EQUIVALENT CIRCUIT

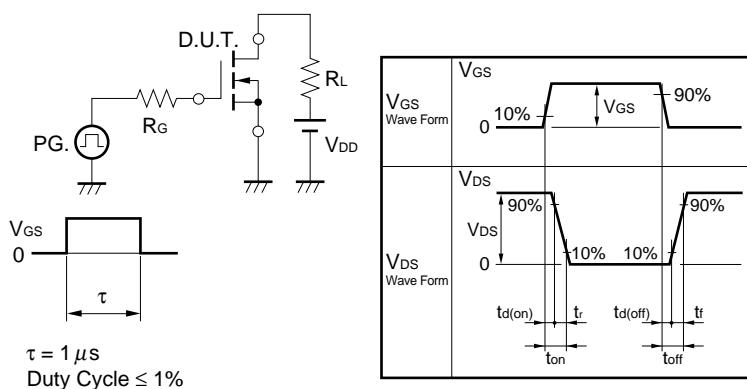


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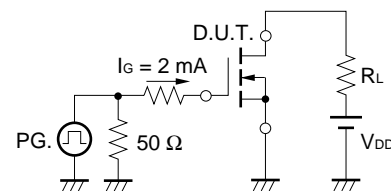
ELECTRICAL CHARACTERISTICS ( $T_A = 25^\circ\text{C}$ )

CHARACTERISTICS	SYMBOL	TEST CONDITIONS	MIN.	TYP.	MAX.	UNIT
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = 20\text{ V}, V_{GS} = 0\text{ V}$			10	$\mu\text{A}$
Gate Leakage Current	$I_{GSS}$	$V_{GS} = \pm 12\text{ V}, V_{DS} = 0\text{ V}$			$\pm 10$	$\mu\text{A}$
Gate Cut-off Voltage	$V_{GS(off)}$	$V_{DS} = 10\text{ V}, I_D = 1.0\text{ mA}$	0.5	1.0	1.5	V
Forward Transfer Admittance	$ y_{fs} $	$V_{DS} = 10\text{ V}, I_D = 5.0\text{ A}$	5.0			S
Drain to Source On-state Resistance	$R_{DS(on)1}$	$V_{GS} = 4.5\text{ V}, I_D = 5.0\text{ A}$	8.0	10.0	13.0	$\text{m}\Omega$
	$R_{DS(on)2}$	$V_{GS} = 4.0\text{ V}, I_D = 5.0\text{ A}$	8.5	10.5	13.5	$\text{m}\Omega$
	$R_{DS(on)3}$	$V_{GS} = 3.1\text{ V}, I_D = 5.0\text{ A}$	9.0	11.5	15.5	$\text{m}\Omega$
	$R_{DS(on)4}$	$V_{GS} = 2.5\text{ V}, I_D = 5.0\text{ A}$	10.0	13.5	18.0	$\text{m}\Omega$
Input Capacitance	$C_{iss}$	$V_{DS} = 10\text{ V}$		1200		pF
Output Capacitance	$C_{oss}$	$V_{GS} = 0\text{ V}$		370		pF
Reverse Transfer Capacitance	$C_{rss}$	$f = 1.0\text{ MHz}$		270		pF
Turn-on Delay Time	$t_{d(on)}$	$V_{DD} = 10\text{ V}, I_D = 5.0\text{ A}$		60		ns
Rise Time	$t_r$	$V_{GS} = 4.0\text{ V}$		350		ns
Turn-off Delay Time	$t_{d(off)}$	$R_G = 10\ \Omega$		450		ns
Fall Time	$t_f$			640		ns
Total Gate Charge	$Q_G$	$V_{DD} = 16\text{ V}$		15		nC
Gate to Source Charge	$Q_{GS}$	$V_{GS} = 4.0\text{ V}$		2.0		nC
Gate to Drain Charge	$Q_{GD}$	$I_D = 10\text{ A}$		8.0		nC
Body Diode Forward Voltage	$V_{F(S-D)}$	$I_F = 10\text{ A}, V_{GS} = 0\text{ V}$		0.83		V
Reverse Recovery Time	$t_{rr}$	$I_F = 10\text{ A}, V_{GS} = 0\text{ V}$		470		ns
Reverse Recovery Charge	$Q_{rr}$	$di/dt = 50\text{ A}/\mu\text{s}$		990		nC

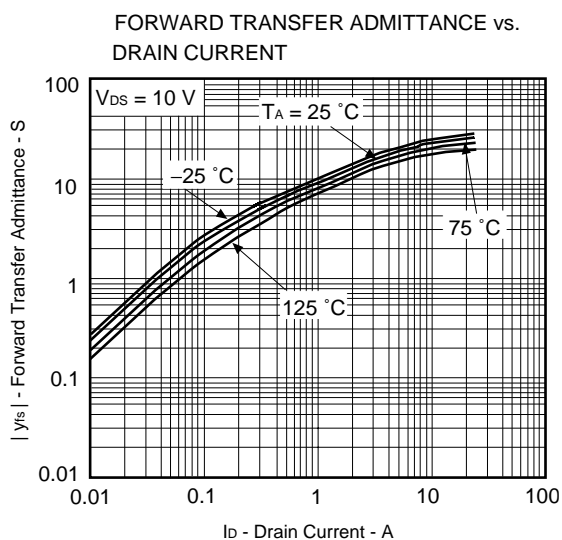
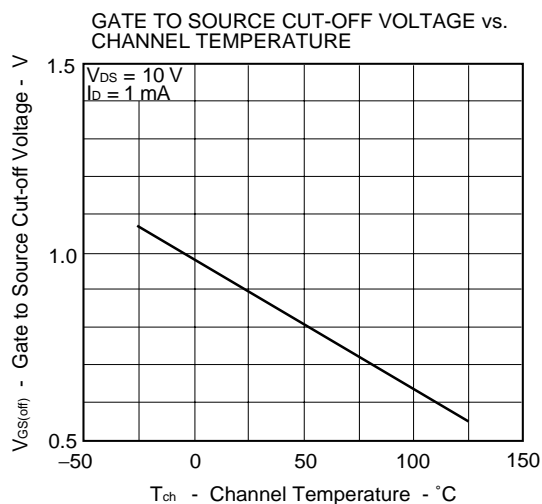
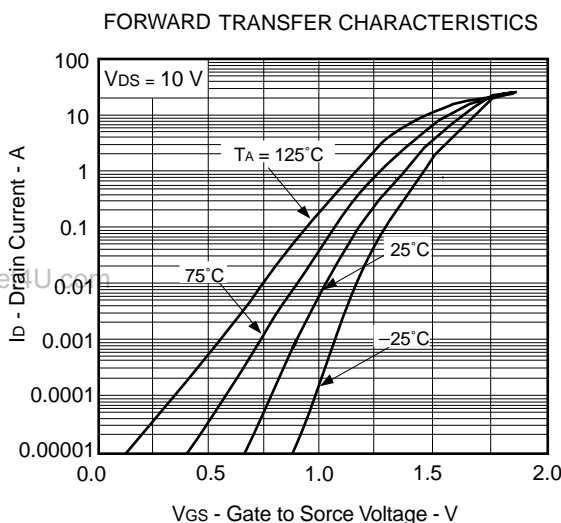
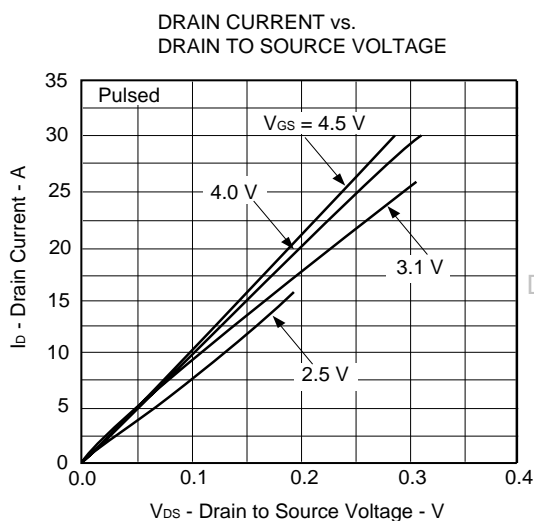
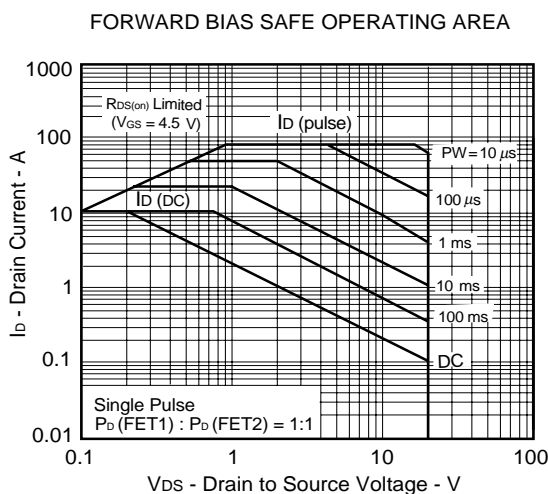
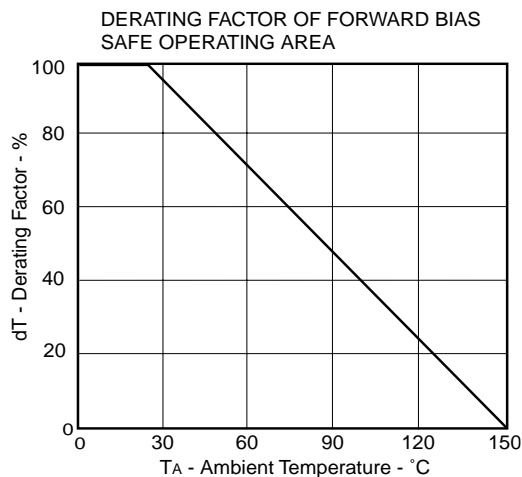
## TEST CIRCUIT 1 SWITCHING TIME

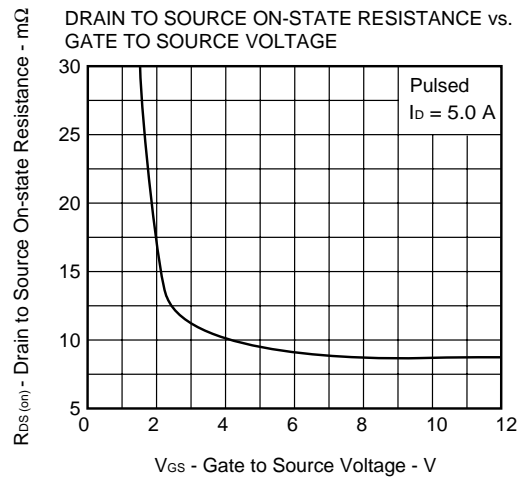
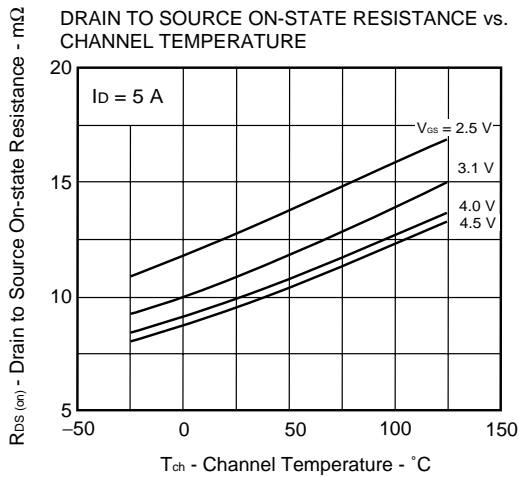
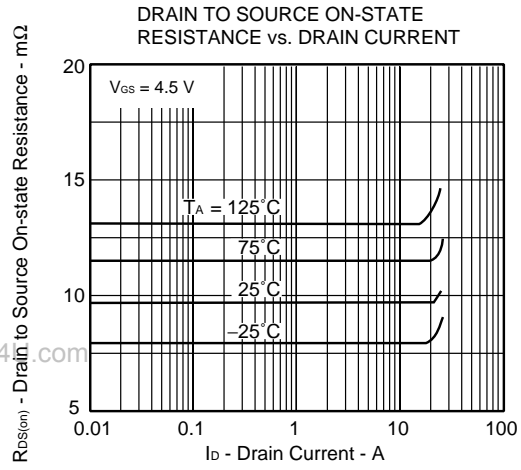
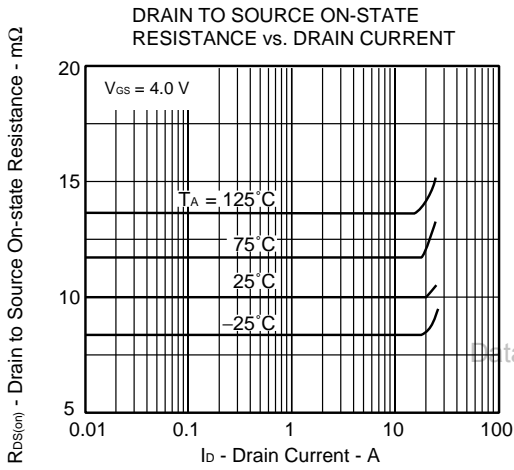
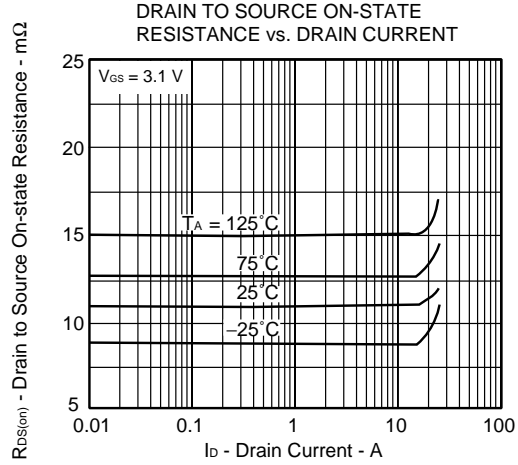
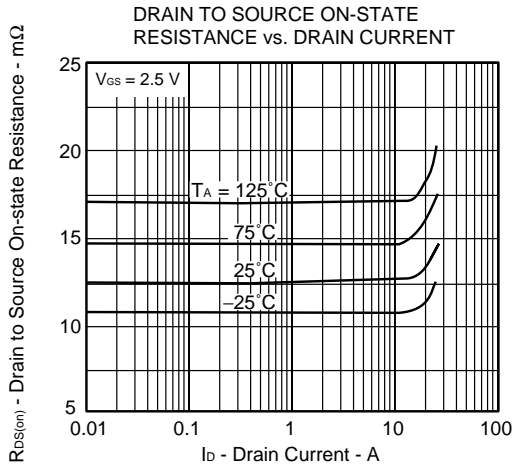


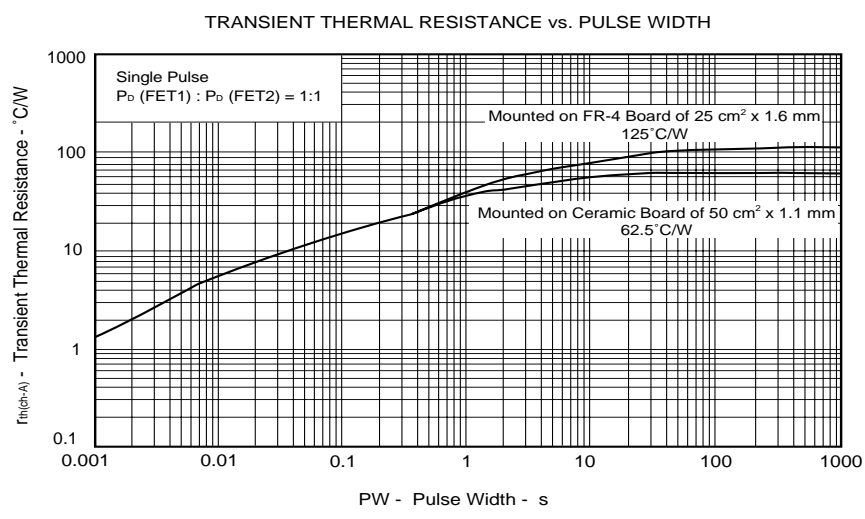
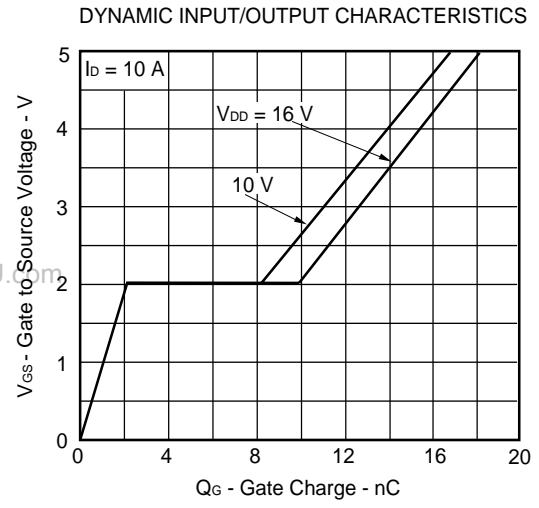
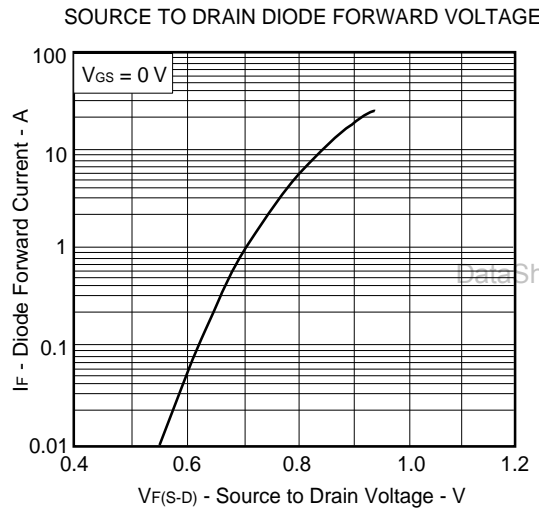
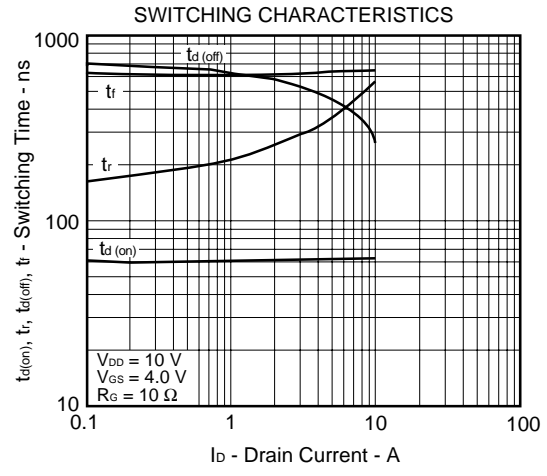
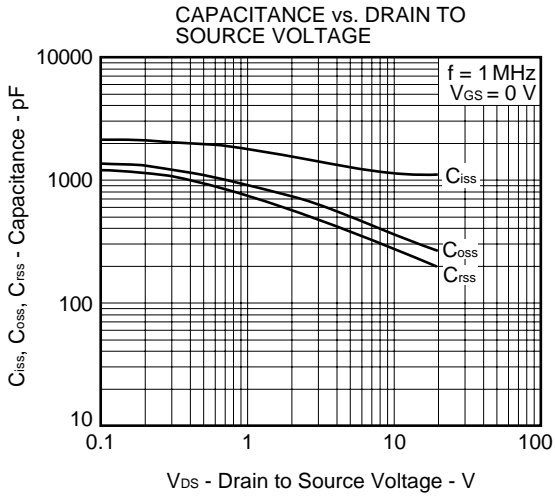
## TEST CIRCUIT 2 GATE CHARGE



TYPICAL CHARACTERISTICS (T<sub>A</sub> = 25°C)







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